Single D-type flip-flop with set and reset; positive edge trigger Rev. 6 — 18 August 2023

1. General description

The 74LVC1G74-Q100 is a single positive edge triggered D-type flip-flop with individual data (D), clock (CP), set (\overline{SD}) and reset (\overline{RD}) inputs, and complementary Q and \overline{Q} outputs. Data at the D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition will be stored in the flip-flop and appear at the Q output. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Direct interface with TTL levels
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options

ne<mark>x</mark>peria

3. Ordering information

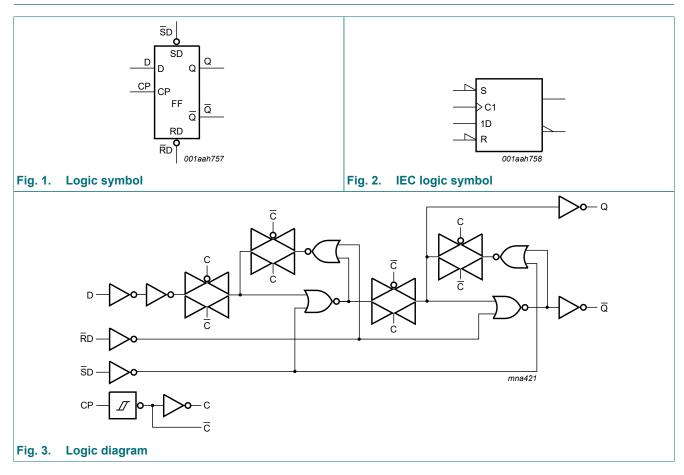
| Type number | Package | | | | | | | |
|------------------|-------------------|--------|--|-----------------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74LVC1G74DP-Q100 | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | <u>SOT505-2</u> | | | | |
| 74LVC1G74DC-Q100 | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | <u>SOT765-1</u> | | | | |
| 74LVC1G74GT-Q100 | -40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | <u>SOT833-1</u> | | | | |

4. Marking

| Table 2. Marking codes | | | | | |
|------------------------|------------------|--|--|--|--|
| Type number | Marking code [1] | | | | |
| 74LVC1G74DP-Q100 | V74 | | | | |
| 74LVC1G74DC-Q100 | V74 | | | | |
| 74LVC1G74GT-Q100 | V74 | | | | |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

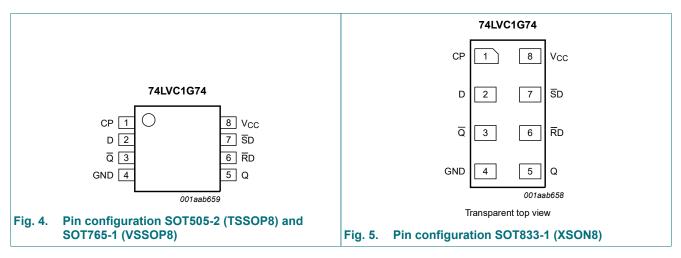
5. Functional diagram



74LVC1G74_Q100

6. Pinning information





6.2. Pin description

| Table 3. Pin description | n | |
|--------------------------|-----|--|
| Symbol | Pin | Description |
| СР | 1 | clock input (LOW-to-HIGH, edge-triggered) |
| D | 2 | data input |
| Q | 3 | complement output |
| GND | 4 | ground (0 V) |
| Q | 5 | true output |
| RD | 6 | asynchronous reset-direct input (active LOW) |
| SD | 7 | asynchronous set-direct input (active LOW) |
| V _{CC} | 8 | supply voltage |

7. Functional description

Table 4. Function table for asynchronous operation

H = HIGH voltage level; L = LOW voltage level; X = don't care.

| Input | | | | Output | | |
|-------|----|----|---|--------|---|--|
| SD | RD | СР | D | Q | Q | |
| L | Н | Х | Х | Н | L | |
| Н | L | Х | Х | L | Н | |
| L | L | Х | Х | Н | Н | |

Table 5. Function table for synchronous operation

H = HIGH voltage level; L = LOW voltage level; $\uparrow = LOW$ -to-HIGH CP transition;

 Q_{n+1} = state after the next LOW-to-HIGH CP transition.

| • | | | | Output | | |
|----|----|----|---|------------------|-------|--|
| SD | RD | СР | D | Q _{n+1} | Q n+1 | |
| Н | Н | 1 | L | L | Н | |
| Н | Н | 1 | Н | Н | L | |

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--------------------------------------|-----|------|-----------------------|------|
| V _{CC} | supply voltage | | | -0.5 | +6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -50 | - | mA |
| VI | input voltage | | [1] | -0.5 | +6.5 | V |
| Ι _{ΟΚ} | output clamping current | $V_{O} > V_{CC}$ or $V_{O} < 0 V$ | | - | ±50 | mA |
| Vo | output voltage | Active mode | [1] | -0.5 | V _{CC} + 0.5 | V |
| | | Power-down mode; $V_{CC} = 0 V$ | [1] | -0.5 | +6.5 | V |
| lo | output current | $V_{O} = 0 V$ to V_{CC} | | - | ±50 | mA |
| I _{CC} | supply current | | | - | 100 | mA |
| I _{GND} | ground current | | | -100 | - | mA |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [2] | - | 250 | mW |
| T _{stg} | storage temperature | | | -65 | +150 | °C |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT505-2 (TSSOP8) package: P_{tot} derates linearly with 4.6 mW/K above 96 °C.

For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 °C.

9. Recommended operating conditions

Table 7. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|-----------------------------------|------|-----------------|------|
| V _{CC} | supply voltage | | 1.65 | 5.5 | V |
| VI | input voltage | | 0 | 5.5 | V |
| Vo | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V_{CC} = 0 V | 0 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 1.65 V to 2.7 V | - | 20 | ns/V |
| | | V_{CC} = 2.7 V to 5.5 V | - | 10 | ns/V |

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | T _{amb} = | -40 °C to | +85 °C | T _{an} -40 °C to | Unit | |
|------------------|------------------------------|--|-----------------------|-----------|---------------------|------------------------------|---------------------|----|
| | | | Min | Typ [1] | Max | Min | Мах | |
| VIH | HIGH-level input | V _{CC} = 1.65 V to 1.95 V | 0.65V _{CC} | - | - | 0.65V _{CC} | - | V |
| | voltage | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | 2.0 | - | V |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7V _{CC} | - | - | 0.7V _{CC} | - | V |
| VIL | LOW-level input | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35V _{CC} | - | 0.35V _{CC} | V |
| | voltage | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | - | 0.7 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | - | 0.8 | V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3V _{CC} | - | 0.3V _{CC} | V |
| V _{OH} | HIGH-level output | V _I = V _{IH} or V _{IL} | | | | | | |
| 0.1 | voltage | I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | - | - | V _{CC} - 0.1 | - | V |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 1.2 | 1.54 | - | 0.95 | - | V |
| | | I _O = -8 mA; V _{CC} = 2.3 V | 1.9 | 2.15 | - | 1.7 | - | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | 2.50 | - | 1.9 | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.3 | 2.62 | - | 2.0 | - | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.8 | 4.11 | - | 3.4 | - | V |
| V _{OL} | LOW-level output | V _I = V _{IH} or V _{IL} | | | | | | |
| | voltage | I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V | - | - | 0.10 | - | 0.10 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | - | 0.07 | 0.45 | - | 0.70 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | - | 0.12 | 0.30 | - | 0.45 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | 0.17 | 0.40 | - | 0.60 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | 0.33 | 0.55 | - | 0.80 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | - | 0.39 | 0.55 | - | 0.80 | V |
| I | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | ±0.1 | ±1 | - | ±1 | μA |
| I _{OFF} | power-off leakage current | $V_{\rm I} \text{ or } V_{\rm O} = 5.5 \text{ V}; V_{\rm CC} = 0 \text{ V}$ | - | ±0.1 | ±2 | - | ±2 | μA |
| I _{CC} | supply current | V_{I} = 5.5 V or GND; V_{CC} = 1.65 V to 5.5 V; I _O = 0 A | - | 0.1 | 4 | - | 4 | μA |
| ΔI _{CC} | additional supply current | per pin; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V | - | 5 | 500 | - | 500 | μA |
| CI | input capacitance | | - | 4.0 | - | - | - | pF |

[1] All typical values are measured at T_{amb} = 25 °C.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

| Symbol | Parameter | Conditions | T _{amb} : | = -40 °C to | +85 °C | T _{ar} -40 °C to | Unit | |
|------------------|-------------------|---|--------------------|-------------|--------|------------------------------|------|----|
| | | | Min | Typ [1] | Max | Min | Max | |
| t _{pd} | propagation delay | CP to Q, \overline{Q} ; see Fig. 6 [2] |] | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 6.0 | 13.4 | 1.5 | 13.4 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | 1.0 | 3.5 | 7.1 | 1.0 | 7.1 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 3.5 | 7.1 | 1.0 | 7.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 3.5 | 5.9 | 1.0 | 5.9 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 1.0 | 2.5 | 4.1 | 1.0 | 4.1 | ns |
| | | \overline{SD} to Q, \overline{Q} ; see Fig. 7 [2] |] | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 6.0 | 12.9 | 1.5 | 12.9 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | 1.0 | 3.5 | 7.0 | 1.0 | 7.0 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 3.5 | 7.0 | 1.0 | 7.0 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 3.0 | 5.9 | 1.0 | 5.9 | ns |
| | | V_{CC} = 4.5 V to 5.5 V | 1.0 | 2.5 | 4.1 | 1.0 | 4.1 | ns |
| | | \overline{RD} to Q, \overline{Q} ; see Fig. 7 [2] |] | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 5.0 | 12.9 | 1.5 | 12.9 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | 1.0 | 3.5 | 7.0 | 1.0 | 7.0 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 3.5 | 7.0 | 1.0 | 7.0 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 3.0 | 5.9 | 1.0 | 5.9 | ns |
| | | V_{CC} = 4.5 V to 5.5 V | 1.0 | 2.5 | 4.1 | 1.0 | 4.1 | ns |
| t _W | pulse width | CP HIGH or LOW; see Fig. 6 | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 6.2 | - | - | 6.2 | - | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.7 | - | - | 2.7 | - | ns |
| | | V _{CC} = 2.7 V | 2.7 | - | - | 2.7 | - | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.7 | 1.3 | - | 2.7 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | ns |
| | | SD and RD LOW; see Fig. 7 | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 6.2 | - | - | 6.2 | - | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.7 | - | - | 2.7 | - | ns |
| | | V _{CC} = 2.7 V | 2.7 | - | - | 2.7 | - | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.7 | 1.6 | - | 2.7 | - | ns |
| | | V_{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | ns |
| t _{rec} | recovery time | SD or RD; see Fig. 7 | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.9 | - | - | 1.9 | - | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.4 | - | - | 1.4 | - | ns |
| | | V _{CC} = 2.7 V | 1.3 | - | - | 1.3 | - | ns |
| | | V _{CC} = 3.0 V to 3.6 V | +1.2 | -3.0 | - | +1.2 | - | ns |
| | | V_{CC} = 4.5 V to 5.5 V | 1.0 | - | - | 1.0 | - | ns |

Single D-type flip-flop with set and reset; positive edge trigger

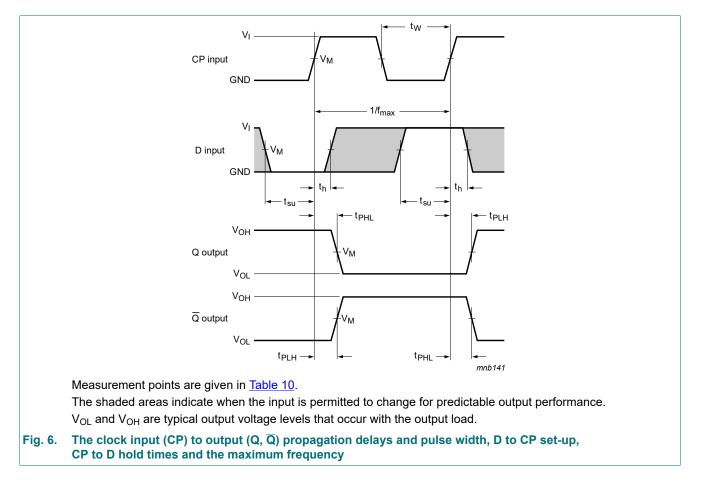
| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | | | _{nb} = c +125 °C | Unit |
|------------------|-------------------------------|--|-------------------------------------|---------|-----|-----|------------------------------|------|
| | | - | Min | Typ [1] | Max | Min | Max | |
| t _{su} | set-up time | D to CP; see Fig. 6 | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 2.9 | - | - | 2.9 | - | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | ns |
| | | V _{CC} = 2.7 V | 1.7 | - | - | 1.7 | - | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.3 | 0.5 | - | 1.3 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 1.1 | - | - | 1.1 | - | ns |
| t _h | hold time | D to CP; see Fig. 6 | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | - | - | 1.5 | - | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.0 | - | - | 1.0 | - | ns |
| | | V _{CC} = 2.7 V | 1.0 | - | - | 1.0 | - | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 0.6 | - | 1.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 1.0 | - | - | 1.0 | - | ns |
| f _{max} | maximum | CP; see <u>Fig. 6</u> | | | | | | |
| | frequency | V _{CC} = 1.65 V to 1.95 V | 80 | - | - | 80 | - | MHz |
| | | V _{CC} = 2.3 V to 2.7 V | 175 | - | - | 175 | - | MHz |
| | | V _{CC} = 2.7 V | 175 | - | - | 175 | - | MHz |
| | | V _{CC} = 3.0 V to 3.6 V | 175 | 280 | - | 175 | - | MHz |
| | | V _{CC} = 4.5 V to 5.5 V | 200 | - | - | 200 | - | MHz |
| C _{PD} | power dissipation capacitance | $V_1 = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [3] | - | 15 | - | - | - | pF |

Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively. [1]

[2]

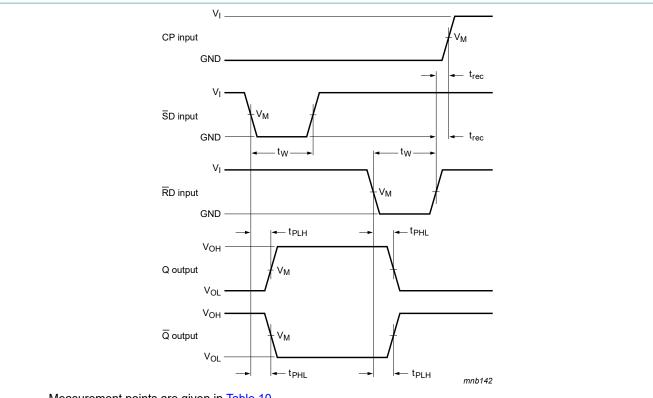
 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: [3] f_i = input frequency in MHz; f_o = output frequency in MHz;

 C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.



11.1. Waveforms and test circuit

74LVC1G74_Q100



Single D-type flip-flop with set and reset; positive edge trigger

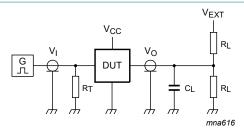
Measurement points are given in Table 10.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 7. The set (\overline{SD}) and reset (\overline{RD}) input to output (Q, \overline{Q}) propagation delays, pulse widths and the \overline{RD} to CP recovery time

Table 10. Measurement points

| Supply voltage | Input | Output | |
|------------------|-----------------------|-----------------------|--|
| V _{cc} | V _M | V _M | |
| 1.65 V to 1.95 V | 0.5 × V _{CC} | 0.5 × V _{CC} | |
| 2.3 V to 2.7 V | $0.5 \times V_{CC}$ | 0.5 × V _{CC} | |
| 2.7 V | 1.5 V | 1.5 V | |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V | |
| 4.5 V to 5.5 V | 0.5 × V _{CC} | $0.5 \times V_{CC}$ | |



Test data is given in <u>Table 11</u>.

Definitions for test circuit:

R_L = Load resistance.

 C_{L} = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage Input | | | Load | | V _{EXT} | V _{EXT} | | |
|----------------------|-----------------|---------------------------------|-------|-------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| V _{cc} | VI | t _r , t _f | CL | RL | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 1.65 V to 1.95 V | V _{CC} | ≤ 2.0 ns | 30 pF | 1 kΩ | open | GND | $2 \times V_{CC}$ | |
| 2.3 V to 2.7 V | V _{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open | GND | $2 \times V_{CC}$ | |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6 V | |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6 V | |
| 4.5 V to 5.5 V | V _{CC} | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | $2 \times V_{CC}$ | |

12. Package outline

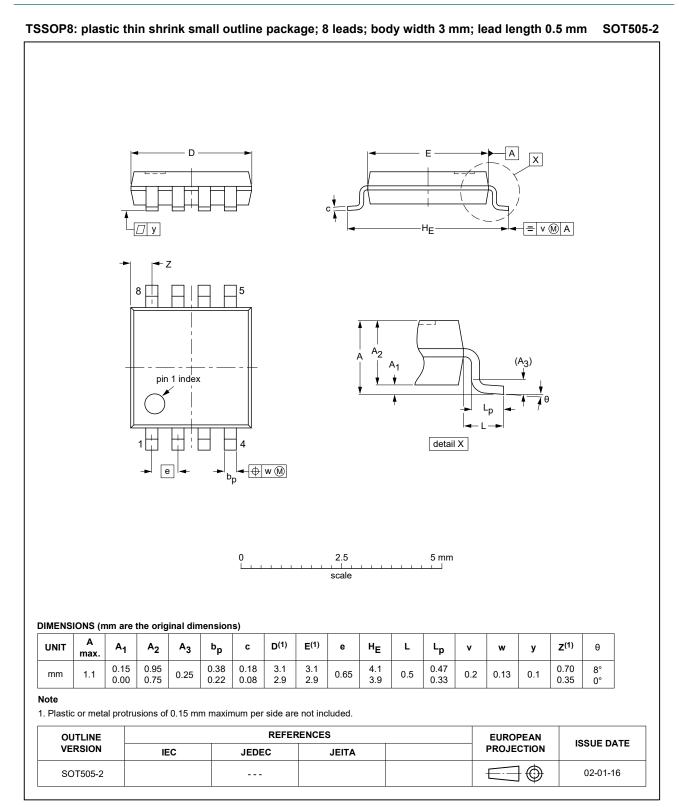


Fig. 9. Package outline SOT505-2 (TSSOP8)

Single D-type flip-flop with set and reset; positive edge trigger

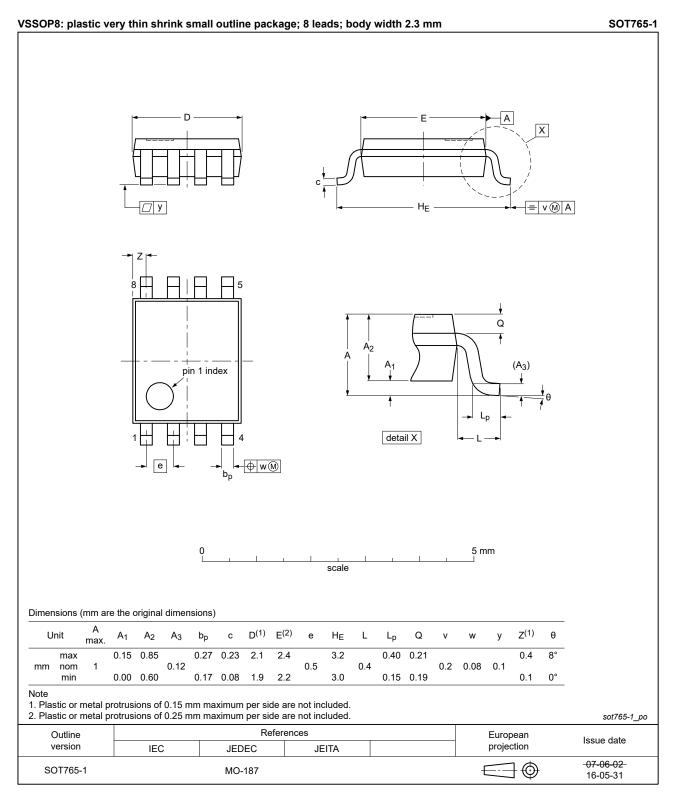


Fig. 10. Package outline SOT765-1 (VSSOP8)

Single D-type flip-flop with set and reset; positive edge trigger

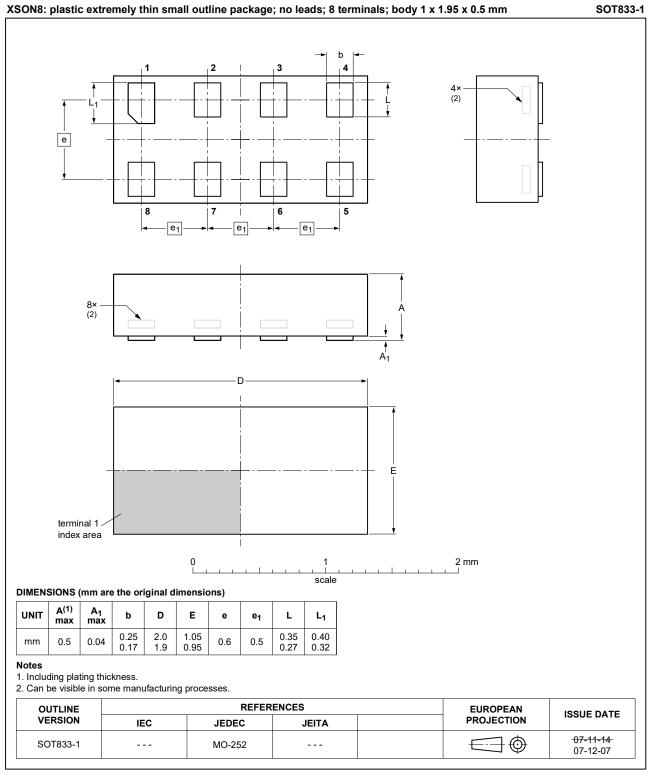


Fig. 11. Package outline SOT833-1 (XSON8)

13. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|--------------------|--|--|---------------|--------------------|--|--|
| 74LVC1G74_Q100 v.6 | 20230818 | Product data sheet | - | 74LVC1G74_Q100 v.5 | | |
| Modifications: | Section 2: E | • <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard. | | | | |
| 74LVC1G74_Q100 v.5 | 20210920 | Product data sheet | - | 74LVC1G74_Q100 v.4 | | |
| Modifications: | | <u>Section 1</u> and <u>Section 2</u> updated. <u>Section 8</u>: Derating values for P_{tot} total power dissipation updated. | | | | |
| 74LVC1G74_Q100 v.4 | 20181105 | Product data sheet | - | 74LVC1G74_Q100 v.3 | | |
| Modifications: | guidelines o Legal texts Type number | ude lines of Nexperia. Legal texts have been adapted to the new company name where appropriate. | | | | |
| 74LVC1G74_Q100 v.3 | 20161209 | Product data sheet | - | 74LVC1G74_Q100 v.2 | | |
| Modifications: | • <u>Table 8</u> : The | • <u>Table 8</u> : The maximum limits for leakage current and supply current have changed. | | | | |
| 74LVC1G74_Q100 v.2 | 20130514 | Product data sheet | - | 74LVC1G74_Q100 v.1 | | |
| Modifications: | • 74LVC1G74 | 74LVC1G74GD-Q100 (XSON8) added. | | | | |
| 74LVC1G74_Q100 v.1 | 20120807 | Product data sheet | - | - | | |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <u>http://www.nexperia.com/profile/terms</u>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

| 1 |
|----|
| 1 |
| 2 |
| 2 |
| 2 |
| 3 |
| 3 |
| 3 |
| 3 |
| 4 |
| 4 |
| 5 |
| 6 |
| 8 |
| 11 |
| 14 |
| 14 |
| |
| |

© Nexperia B.V. 2023. All rights reserved

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 18 August 2023